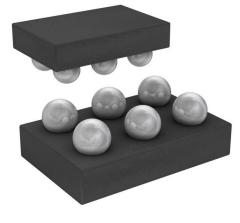


# **FPF1321BUCX** Datasheet

www.digi-electronics.com



DiGi Electronics Part Number	FPF1321BUCX-DG
Manufacturer	onsemi
Manufacturer Product Number	FPF1321BUCX
Description	IC PWR SWITCH P-CHAN 2:1 6WLCSP
Detailed Description	Power Switch/Driver 2:1 P-Channel 1.5A 6-WLCSP 0.96x1.66)

https://www.DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



# Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
FPF1321BUCX	onsemi
Series:	Product Status:
IntelliMAX™	Obsolete
Switch Type:	Number of Outputs:
General Purpose	1
Ratio - Input:Output:	Output Configuration:
2:1	High Side
Output Type:	Interface:
P-Channel	On/Off
Voltage - Load:	Voltage - Supply (Vcc/Vdd):
1.5V ~ 5.5V	Not Required
Current - Output (Max):	Rds On (Typ):
1.5A	42mOhm
Input Type:	Features:
Non-Inverting	Load Discharge, Slew Rate Controlled
Fault Protection:	Operating Temperature:
Reverse Current	-40°C ~ 85°C (TA)
Mounting Type:	Supplier Device Package:
Surface Mount	6-WLCSP (0.96x1.66)
Package / Case:	Base Product Number:
6-UFBGA, WLCSP	FPF1321

# **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.29.0095	

# onsemi

# IntelliMAX<sup>™</sup> Dual-Input Single-Output Advanced Power Switch with True Reverse-Current Blocking

# FPF1320, FPF1321

## Description

The FPF1320/21 is a Dual–Input Single–Output (DISO) load switch consisting of two sets of slew–rate controlled, low on–resistance, P–channel MOSFET switches and integrated analog features. The slew–rate–controlled turn–on characteristic prevents inrush current and the resulting excessive voltage droop on the power rails. The input voltage range operates from 1.5 V to 5.5 V to align with the requirements of low–voltage portable device power rails. FPF1320/21 performs seamless power–source transitions between two input power rails using the SEL pin with advanced break–before–make operation.

FPF1320/21 has a TRCB function to block unwanted reverse current from output to input during ON/OFF states. The switch is controlled by logic inputs of the SEL and EN pins, which are capable of interfacing directly with low–voltage control signals (GPIO).

FPF1321 has 65  $\Omega$  on-chip load resistor for output quick discharge when EN is LOW.

FPF1320/21 is available in 1.0 mm x 1.5 mm WLCSP, 6-bump, with 0.5 mm pitch. FPF1321B is available in 1.0 mm x 1.5 mm WLCSP, 6-bump, 0.5 mm pitch with backside laminate.

## Features

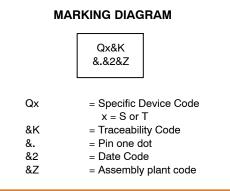
- DISO Load Switches
- Input Supply Operating Range: 1.5 V ~ 5.5 V
- $R_{ON}$  50 m $\Omega$  at  $V_{IN}$  = 3.3 V Per Channel (Typical)
- True Reverse Current Blocking (TRCB)
- Fixed Slew Rate Controlled 130  $\mu$ s for < 1  $\mu$ F C<sub>OUT</sub>
- I<sub>SW</sub>: 1.5 A Per Channel (Maximum)
- Quick Discharge Feature on FPF1321
- Logic CMOS IO Meets JESD76 Standard for GPIO Interface and Related Power Supply Requirements
- ESD Protected:
  - ◆ Human Body Model: > 6 kV
  - ◆ Charged Device Model: > 1.5 kV
  - ◆ IEC 61000-4-2 Air Discharge: > 15 kV
  - ◆ IEC 61000-4-2 Contact Discharge: > 8 kV
- These are Pb-Free and Halide Free Devices

### Applications

- Smart Phones / Tablet PCs
- Portable Devices
- Near Field Communication (NFC) Capable SIM Card Power Supply



WLCSP-6 CASE 567RM



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 12 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page See detailed ordering and shipping information on page 12 of this data sheet.

# **APPLICATION DIAGRAM**

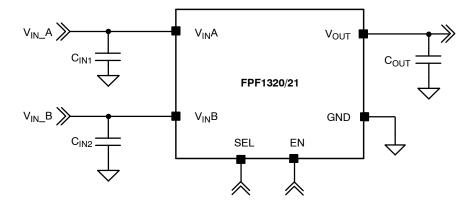
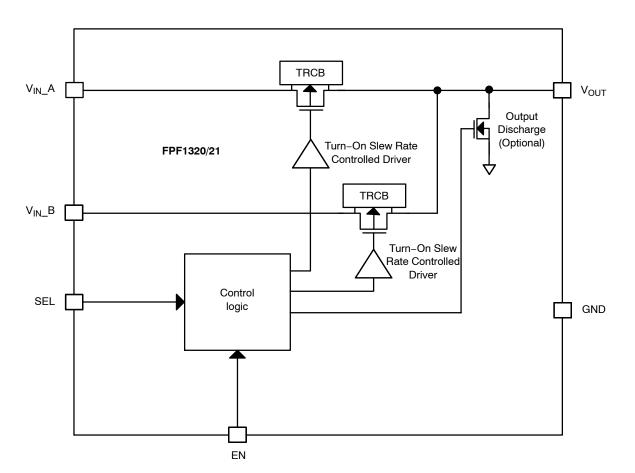


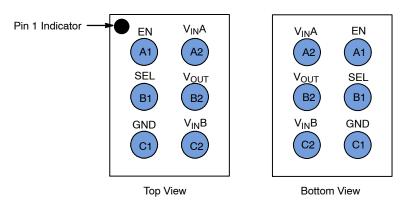
Figure 1. Typical Application



# **BLOCK DIAGRAM**

Figure 2. Functional Block Diagram (Output Discharge Path for FPF1321 Only)

# **PIN CONFIGURATION**





## PIN DESCRIPTION

Pin #	Name	Description
A1	EN	Enable input. Active HIGH. There is an internal pull-down resistor at the EN pin.
B1	SEL	Input power selection inputs. See Truth Table. There are internal pull-down resistors at the SEL pins.
A2	V <sub>IN</sub> A	Supply Input. Input to the power switch A.
B2	V <sub>OUT</sub>	Switch output
C1	GND	Ground
C2	V <sub>IN</sub> B	Supply Input. Input to power switch B.

# TRUTH TABLE

SEL	EN	Switch A	Switch B	V <sub>OUT</sub>	Status
Low	High	ON	OFF	V <sub>IN</sub> A	V <sub>IN</sub> A Selected
High	High	OFF	ON	V <sub>IN</sub> B	V <sub>IN</sub> B Selected
X	Low	OFF	OFF	Floating for FPF1320 GND for FPF1321	Both Switches are OFF

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Pa	arameters	Min	Max	Unit
V <sub>IN</sub>	$V_{IN}A$ , $V_{IN}B$ , $V_{SEL}$ , $V_{EN}$ , $V_{OUT}$ to GN	$_{N}A$ , $V_{IN}B$ , $V_{SEL}$ , $V_{EN}$ , $V_{OUT}$ to GND			
I <sub>SW</sub>	Maximum Continuous Switch Curre	-	1.5	А	
PD	Total Power Dissipation at T <sub>A</sub> = 25°0	-	1.2	W	
T <sub>STG</sub>	Operating and Storage Junction Ter	-65	150	°C	
$\Theta_{JA}$		Thermal Resistance, Junction-to-Ambient (1 in. <sup>2</sup> Pad of 2-oz. Copper)		85 (Note 1)	°C/W
	(1 In. <sup>2</sup> Pad of 2–oz. Copper)			110 (Note 2)	
ESD	Electrostatic Discharge Capability	Human Body Model, JESD22-A114	6.0	-	kV
		Charged Device Model, JESD22-C101	1.5	-	
		Air Discharge (V <sub>IN</sub> A, V <sub>IN</sub> B to GND), IEC61000-4-2 System Level	15.0	-	
		Contact Discharge (V <sub>IN</sub> A, V <sub>IN</sub> B to GND), IEC61000-4-2 System Level	8.0	-	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured using 2S2P JEDEC std. PCB.

2. Measured using 2S2P JEDEC PCB cold-plate method.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameters	Min	Max	Unit
V <sub>IN</sub>	Input Voltage on V <sub>IN</sub> A, V <sub>IN</sub> B	1.5	5.5	V
T <sub>A</sub>	Ambient Operating Temperature	-40	85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# **ELECTRICAL CHARACTERISTICS** $V_{IN}A = V_{IN}B = 1.5$ to 5.5 V, $T_A = -40$ to 85°C unless otherwise noted. Typical values are at $V_{IN}A = V_{IN}B = 3.3$ V, $T_A = 25$ °C

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
BASIC OPERA	TION			-		
V <sub>IN</sub> A, V <sub>IN</sub> B	Input Voltage	-	1.5	-	5.5	V
I <sub>SD</sub>	Shutdown Current	SEL = HIGH or LOW, EN = GND, V <sub>OUT</sub> = GND, V <sub>IN</sub> A = V <sub>IN</sub> B = 5.5 V	-	-	5	μΑ
Ι <sub>Q</sub>	Quiescent Current	_	12	22	μΑ	
	On-Resistance	$V_{IN}A = V_{IN}B = 5.5 \text{ V},$ $I_{OUT} = 200 \text{ mA}, \text{ T}_A = 25^{\circ}\text{C}$	-	42	60	mΩ
R <sub>ON</sub>		$\label{eq:VINA} \begin{split} V_{IN} A &= V_{IN} B = 3.3 \text{ V}, \\ I_{OUT} &= 200 \text{ mA},  T_A = 25^{\circ}\text{C} \end{split}$	-	50	-	
		$V_{IN}A = V_{IN}B = 1.8 \text{ V},$ $I_{OUT} = 200 \text{ mA}, \text{ T}_A = 25^{\circ}\text{C} \text{ to } 85^{\circ}\text{C}$	-	80	-	
		$V_{IN}A = V_{IN}B = 1.5 \text{ V},$ $I_{OUT} = 200 \text{ mA},  T_A = 25^{\circ}\text{C}$	_	-	170	
V <sub>IH</sub>	SEL, EN Input Logic High Voltage	$V_{IN}A, V_{IN}B = 1.5 V - 5.5 V$	1.15	-	-	V
V <sub>IL</sub>	SEL, EN Input Logic Low Voltage	$V_{IN}A, V_{IN}B = 1.8 V - 5.5 V$	-	-	0.65	V
	SEL, EN Input Logic Low Voltage	$V_{IN}A$ , $V_{IN}B$ = 1.5 V – 1.8 V	-	-	0.60	
V <sub>DROOP</sub> OUT	$ \begin{array}{ll} \mbox{Output Voltage Droop while Channel} \\ \mbox{Switching from Higher Input Voltage} \\ \mbox{Lower Input Voltage (Note 3)} \end{array}  \begin{array}{ll} \mbox{V}_{IN}A = 3.3 \ \mbox{V}, \mbox{V}_{IN}B = 5 \ \mbox{V}, \\ \mbox{Switching from V}_{IN}A \rightarrow \mbox{V}_{IN}B, \\ \mbox{R}_L = 150 \ \mbox{\Omega}, \ \mbox{C}_{OUT} = 1 \ \mbox{\mu}F \end{array} $		-	-	100	mV
I <sub>SEL</sub> /I <sub>EN</sub>	Input Leakage at SEL and EN Pin	-	-	-	1.2	μA

**ELECTRICAL CHARACTERISTICS**  $V_{IN}A = V_{IN}B = 1.5$  to 5.5 V,  $T_A = -40$  to 85°C unless otherwise noted. Typical values are at  $V_{IN}A = V_{IN}B = 3.3$  V,  $T_A = 25$ °C (continued)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
BASIC OPER	ATION (continued)					
$R_{SEL_{PD}}/R_{EN_{PD}}$	Pull-Down Resistance at SEL or EN Pin	-	-	7	-	MΩ
R <sub>PD</sub>	Output Pull-Down Resistance	SEL = HIGH or LOW, EN = GND, $I_{FORCE}$ = 20 mA, $T_A$ = 25°C, FPF1321	-	65	-	Ω
RUE REVER	SE CURRENT BLOCKING					
V <sub>T_RCB</sub>	RCB Protection Trip Point	$V_{OUT} - V_{IN}A$ or $V_{IN}B$	-	45	-	mV
V <sub>R_RCB</sub>	RCB Protection Release Trip Point	V <sub>IN</sub> A or V <sub>IN</sub> B –V <sub>OUT</sub>	-	25	-	mV
I <sub>RCB</sub>	V <sub>IN</sub> A or V <sub>IN</sub> B Current During RCB	$V_{OUT} = 5.5 V,$ $V_{IN}A \text{ or } V_{IN}B = \text{Short to GND}$	-	9	15	μΑ
t <sub>RCB_ON</sub>	RCB Response Time w hen Device is ON (Note 3)	$V_{IN}A$ or $V_{IN}B$ = 5 V, $V_{OUT}V_{IN}A$ ,B = 100 mV	-	5	-	μs
OYNAMIC CH	ARACTERISTICS					
t <sub>DON</sub>	Turn-On Delay (Note 4)	$V_{IN}A \text{ or } V_{IN}B = 3.3 \text{ V}, \text{ R}_{L} = 150 \Omega,$	-	120	-	μs
t <sub>R</sub>	V <sub>OUT</sub> Rise Time (Note 4)	C <sub>L</sub> = 1 $\mu$ F, T <sub>A</sub> = 25°C, SEL: HIGH, EN: LOW → HIGH	-	130	-	
t <sub>ON</sub>	Turn-On Time (Note 6)		-	250	-	
t <sub>DOFF</sub>	Turn-Off Delay (Note 4)	$V_{IN}A \text{ or } V_{IN}B = 3.3 \text{ V}, \text{ R}_{L} = 150 \Omega,$	-	15	-	μs
t <sub>F</sub>	V <sub>OUT</sub> Fall Time (Note 4)	$C_L = 1 \ \mu F, T_A = 25^{\circ}C, SEL: HIGH, EN: HIGH \rightarrow LOW$	-	320	-	
t <sub>OFF</sub>	Turn-Off Time (Note 7)		-	335	-	
t <sub>DOFF</sub>	Turn-Off Delay (Note 4, Note 5)	$V_{IN}A \text{ or } V_{IN}B = 3.3 \text{ V}, \text{ R}_{L} = 150 \Omega,$	-	6	-	μs
t <sub>F</sub>	V <sub>OUT</sub> Fall Time (Note 4, Note 5)	C <sub>L</sub> = 1 $\mu$ F, T <sub>A</sub> = 25°C, SEL: HIGH, EN: HIGH→ LOW,	-	110	-	
t <sub>OFF</sub>	Turn-Off Time (Note 5, Note 7)	Output Discharge Mode, FPF1321	-	116	-	
t <sub>TRANR</sub>	Transition Time LOW $\rightarrow$ HIGH (Note 4)	$\label{eq:VINA} \begin{array}{l} V_{IN}A = 3.3 \ V, \ V_{IN}B = 5 \ V, \\ \text{Switching from } V_{IN}A \rightarrow V_{IN}B, \end{array}$	-	3	-	μs
t <sub>SLH</sub>	Switch-Over Rising Delay (Note 4)	SEL: LOW → HIGH, EN: HIGH, R <sub>L</sub> = 150 Ω, C <sub>L</sub> = 1 μF, T <sub>A</sub> = 25°C	_	1	-	
t <sub>TRANF</sub>	Transition Time HIGH $\rightarrow$ LOW (Note 4)	$V_{IN}A = 3.3 \text{ V}, V_{IN}B = 5 \text{ V},$ Switching from $V_{IN}B \rightarrow V_{IN}A$ ,	-	45	-	μs
t <sub>SHL</sub>	Switch-Over Falling Delay (Note 4)	SEL: HIĞH → LOW, EN: HIGH, R <sub>L</sub> = 150 Ω, C = 1 μF, T <sub>A</sub> = 25°C	-	5	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. This parameter is guaranteed by design and characterization; not production tested.

t<sub>DON</sub>/t<sub>DOFF</sub>/t<sub>R</sub>/t<sub>F</sub>/t<sub>TRANR</sub>/t<sub>TRANF</sub>/t<sub>SLH</sub>/t<sub>SHL</sub> are defined in Figure 4.
 FPF1321 output discharge is enabled during off.

6.  $t_{OFF} = t_F + t_{DOFF}$ 7.  $t_{OFF} = t_F + t_{DOFF}$ 

# TIMING DIAGRAM

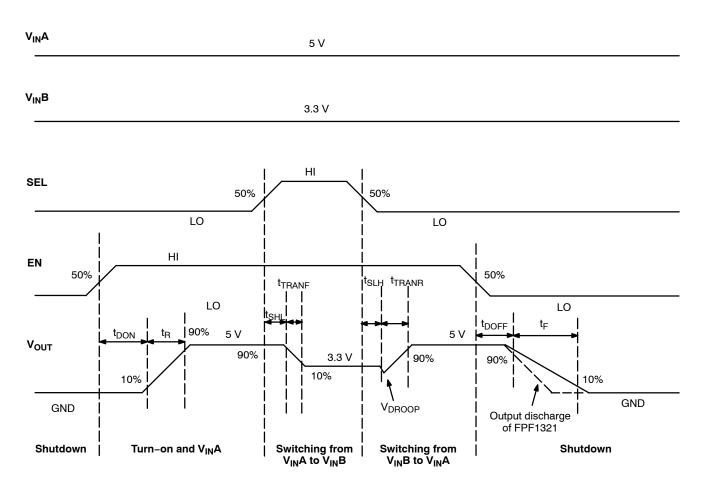
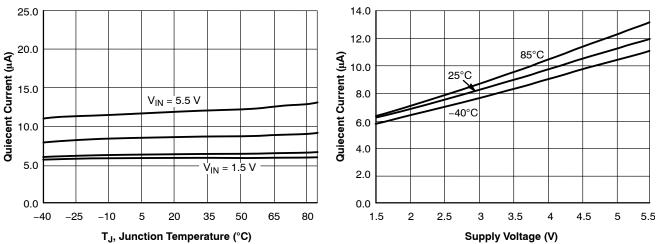
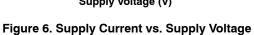


Figure 4. Dynamic Behavior Timing Diagram

#### **TYPICAL CHARACTERISTICS**







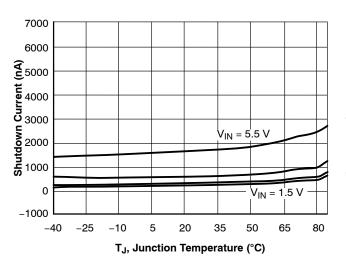
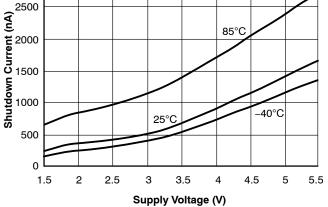
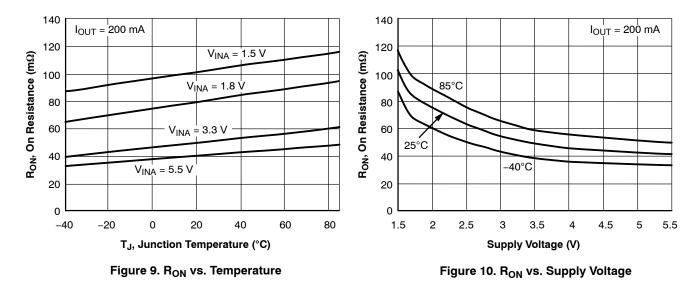


Figure 7. Shutdown Current vs. Temperature

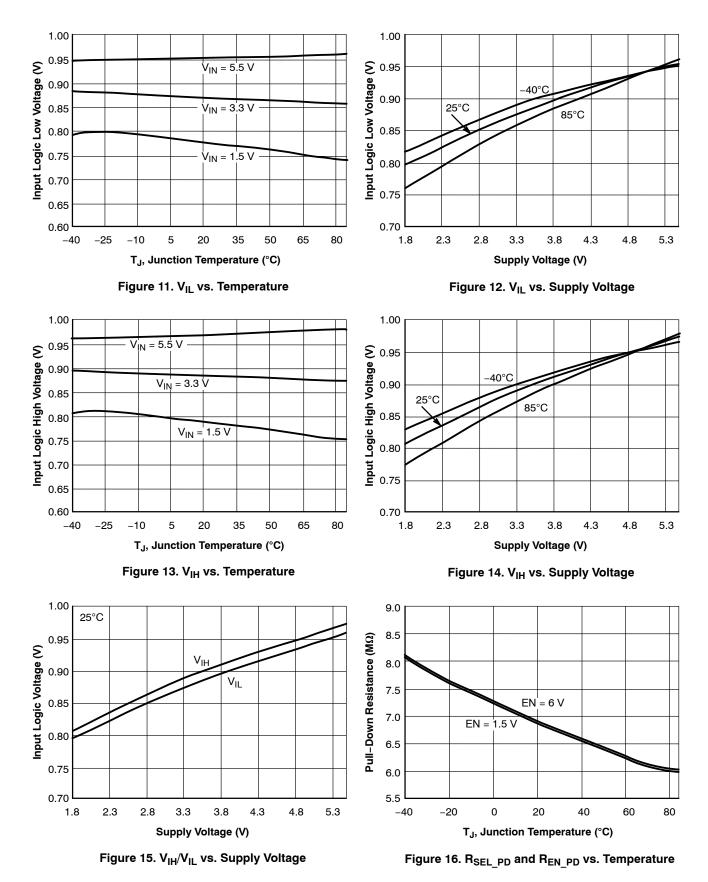




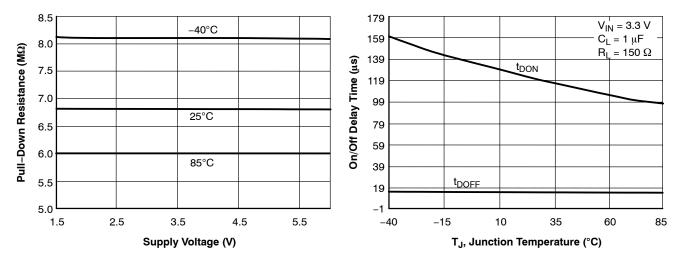




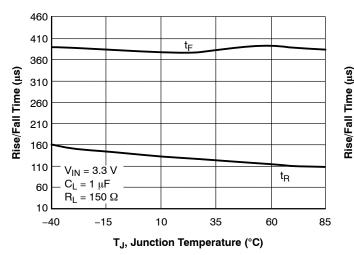
## TYPICAL CHARACTERISTICS (CONTINUED)



## TYPICAL CHARACTERISTICS (CONTINUED)











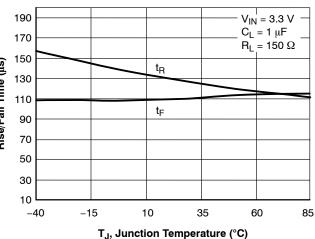


Figure 20.  $t_R$  and  $t_F$  with FPF1321 vs. Temperature

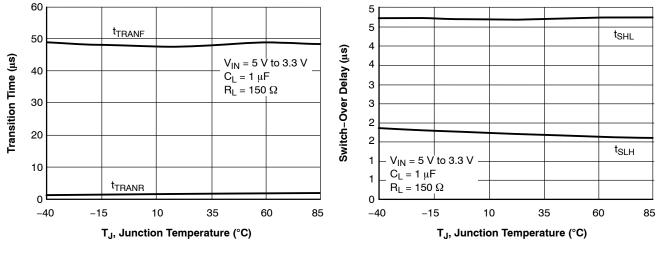
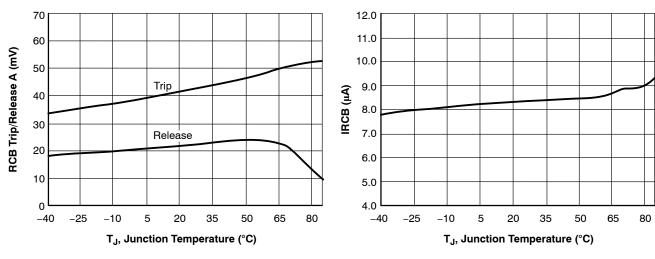




Figure 22. Switch Over Time vs. Temperature

## TYPICAL CHARACTERISTICS (CONTINUED)





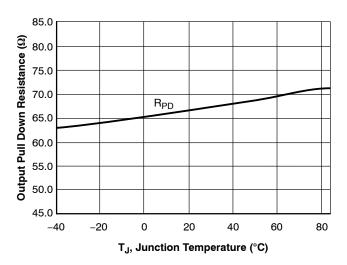


Figure 25. R<sub>PD</sub> with FPF1321 vs. Temperature

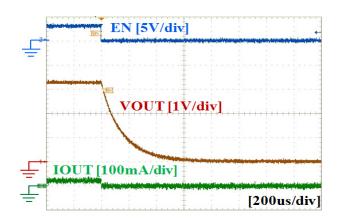
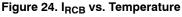


Figure 27. Turn–Off Response with FPF1320 ( $V_{IN}A = 3.3 V$ ,  $C_{IN} = 1 \mu$ F,  $C_{OUT} = 1 \mu$ F,  $R_L = 150 \Omega$ , SEL = LOW)



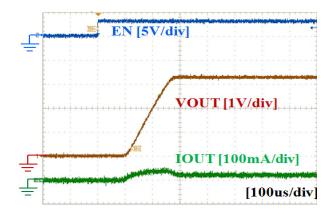
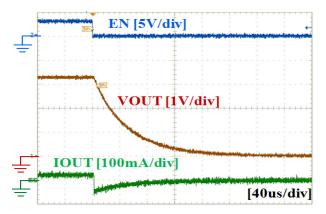
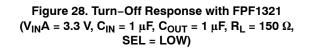


Figure 26. Turn–On Response (V<sub>IN</sub>A = 3.3 V, C<sub>IN</sub> = 1  $\mu$ F, C<sub>OUT</sub> = 1  $\mu$ F, R<sub>L</sub> = 150  $\Omega,$  SEL = LOW)





## TYPICAL CHARACTERISTICS (CONTINUED)

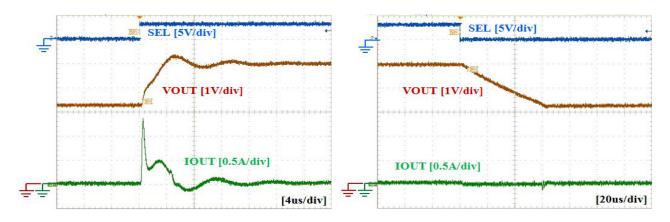


Figure 29. Power Source Transition from 3.3 V to 5 V ( $V_{IN}A = 3.3$  V,  $V_{IN}B = 5$  V,  $C_{IN} = 1 \mu$ F,  $C_{OUT} = 1 \mu$ F,  $R_L = 150 \Omega$ )

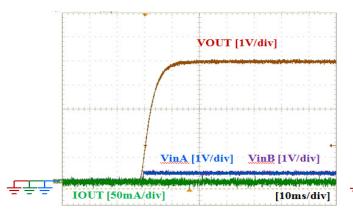


Figure 31. TRCB During Off ( $V_{IN}A = V_{IN}B =$  Floating,  $V_{OUT} = 5 V$ ,  $C_{IN} = 1 \mu$ F,  $C_{OUT} = 1 \mu$ F, EN = LOW, No R<sub>L</sub>)

Figure 30. Power Source Transition from 5 V to 3.3 V (V<sub>IN</sub>A = 3.3 V, V<sub>IN</sub>B = 5 V, C<sub>IN</sub> = 1  $\mu$ F, C<sub>OUT</sub> = 1  $\mu$ F, R<sub>L</sub> = 150  $\Omega$ )

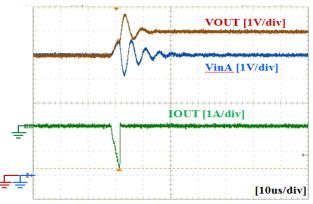


Figure 32. TRCB During On (V<sub>IN</sub>A = 5 V, V<sub>OUT</sub> = 6 V, C<sub>IN</sub> = 1  $\mu$ F, C<sub>OUT</sub> = 1  $\mu$ F, EN = HIGH, No R<sub>L</sub>)

#### **OPERATION AND APPLICATION DESCRIPTION**

The FPF1320 and FPF1321 are dual-input single-output power multiplexer switches with controlled turn-on and seamless power source transition. The core is a 50 m $\Omega$ P-channel MOSFET and controller capable of functioning over a wide input operating range of 1.5 V to 5.5 V per channel. The EN and SEL pins are active-HIGH, GPIO/CMOS-compatible input. They control the state of the switch and input power source selection, respectively. TRCB functionality blocks unwanted reverse current during both ON and OFF states when higher V<sub>OUT</sub> than V<sub>IN</sub>A or V<sub>IN</sub>B is applied. FPF1321 has a 65  $\Omega$  output discharge path during off.

#### **Input Capacitor**

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into a discharged load capacitor; a capacitor must be placed between the  $V_{IN}A$  or  $V_{IN}B$  pins to the GND pin. At least 1  $\mu$ F ceramic capacitor,  $C_{IN}$ , placed close to the pins, is usually sufficient. Higher-value  $C_{IN}$  can be used to reduce more the voltage drop.

#### **Inrush Current**

Inrush current occurs when the device is turned on. Inrush current is dependent on output capacitance and slew rate control capability, as expressed by:

$$I_{INRUSH} = C_{OUT} \times \frac{V_{IN} - V_{INITIAL}}{t_R} + I_{LOAD}$$
 (eq. 1)

where:

 $C_{OUT}$ : Output capacitance; t<sub>R</sub>: Slew rate or rise time at V<sub>OUT</sub>; V<sub>IN</sub>: Input voltage, V<sub>IN</sub>A or V<sub>IN</sub>B; V<sub>INITIAL</sub>: Initial voltage at C<sub>OUT</sub>, usually GND; and I<sub>LOAD</sub>: Load current.

Higher inrush current causes higher input voltage drop, depending on the distributed input resistance and input capacitance. High inrush current can cause problems.

FPF1320/1 has a 130  $\mu$ s of slew rate capability under 3.3 V<sub>IN</sub> at 1  $\mu$ F of C<sub>OUT</sub> and 150  $\Omega$  of R<sub>L</sub> so inrush current and input voltage drop can be minimized.

#### **Power Source Selection**

Input power source selection can be controlled by the SEL pin. When SEL is LOW, output is powered from  $V_{IN}A$  while SEL is HIGH,  $V_{IN}B$  is powering output. The SEL signal is ignored during device OFF.

### **Output Voltage Drop During Transition**

Output voltage drop usually occurs during input power source transition period from low voltage to high voltage. The drop is highly dependent on output capacitance and load current. FPF1320/1 adopts an advanced break-before-make control, which can result in minimized output voltage drop during the transition time.

#### **Output Capacitor**

Capacitor  $C_{OUT}$  of at least 1  $\mu$ F is highly recommended between the  $V_{OUT}$  and GND pins to achieve minimized output voltage drop during input power source transition. This capacitor also prevents parasitic board inductance.

#### **True Reverse-Current Blocking**

The true reverse-current blocking feature protects the input source against current flow from output to input regardless of whether the load switch is on or off.

#### Board Layout

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effect that parasitic trace inductance on normal and short–circuit operation. Wide traces or large copper planes for power pins ( $V_{IN}A$ ,  $V_{IN}B$ ,  $V_{OUT}$  and GND) minimize the parasitic electrical effects and the thermal impedance.

Part Number	Top Mark	Channel	Switch Per Channel (Typ.) at 3.3 V <sub>IN</sub>	Reverse Current Blocking	Output Discharge	Rise Time (t <sub>R</sub> )	Package
FPF1320UCX	QS	DISO	$50 \text{ m}\Omega$	Yes	NA	130 μs	1.0 mm × 1.5 mm Wafer-Level Chip-Scale
FPF1321UCX	QT	DISO	50 m $\Omega$	Yes	65 Ω	130 μs	Package (WLCSP) 6-Bumps, 0.5 mm Pitch

#### **ORDERING INFORMATION**

#### DISCONTINUED (Note 8)

FPF1321BUCX	QT	DISO	50 mΩ	Yes	65 Ω	130 μs	1.0 mm × 1.5 mm Wafer-Level Chip-Scale Package (WLCSP) 6-Bumps, 0.5 mm Pitch with Backside Laminate
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8. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on <u>www.onsemi.com</u>.

#### **PRODUCT-SPECIFIC DIMENSIONS**

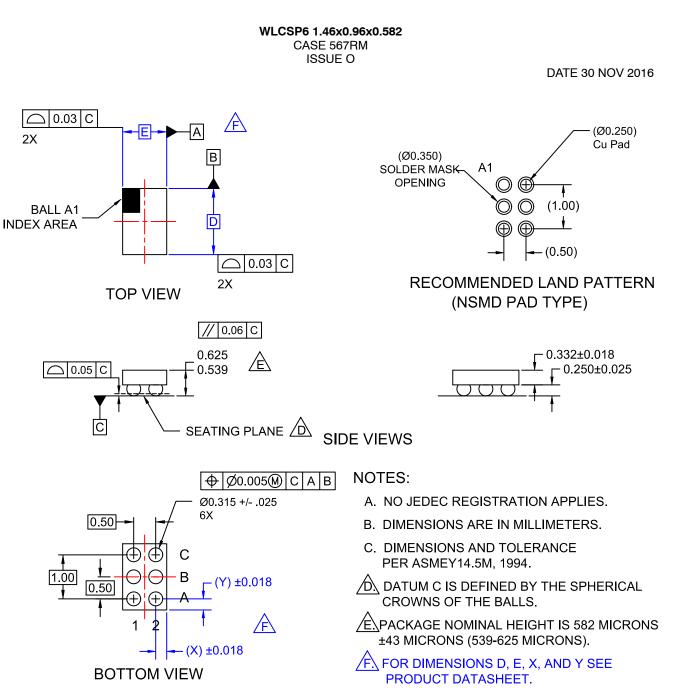
Product	D	E	Х	Y
FPF1320UCX	1460 μm ± 30 μm	960 μm ± 30 μm	230 μm	230 μm
FPF1321UCX	1460 μm ± 30 μm	960 μm ± 30 μm	230 μm	230 µm
FPF1321BUCX	1460 μm ± 30 μm	960 μm ± 30 μm	230 µm	230 µm

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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



 
 DOCUMENT NUMBER:
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 DESCRIPTION:
 WLCSP6 1.46x0.96x0.582
 PAGE 1 OF 1

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FPF1321BUCX onsemi IC PWR SWITCH P-CHAN 2:1 6WLCSP

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